



SRA2219S

PNP Silicon Transistor

Descriptions

- Switching application
- Interface circuit and driver circuit application

Features

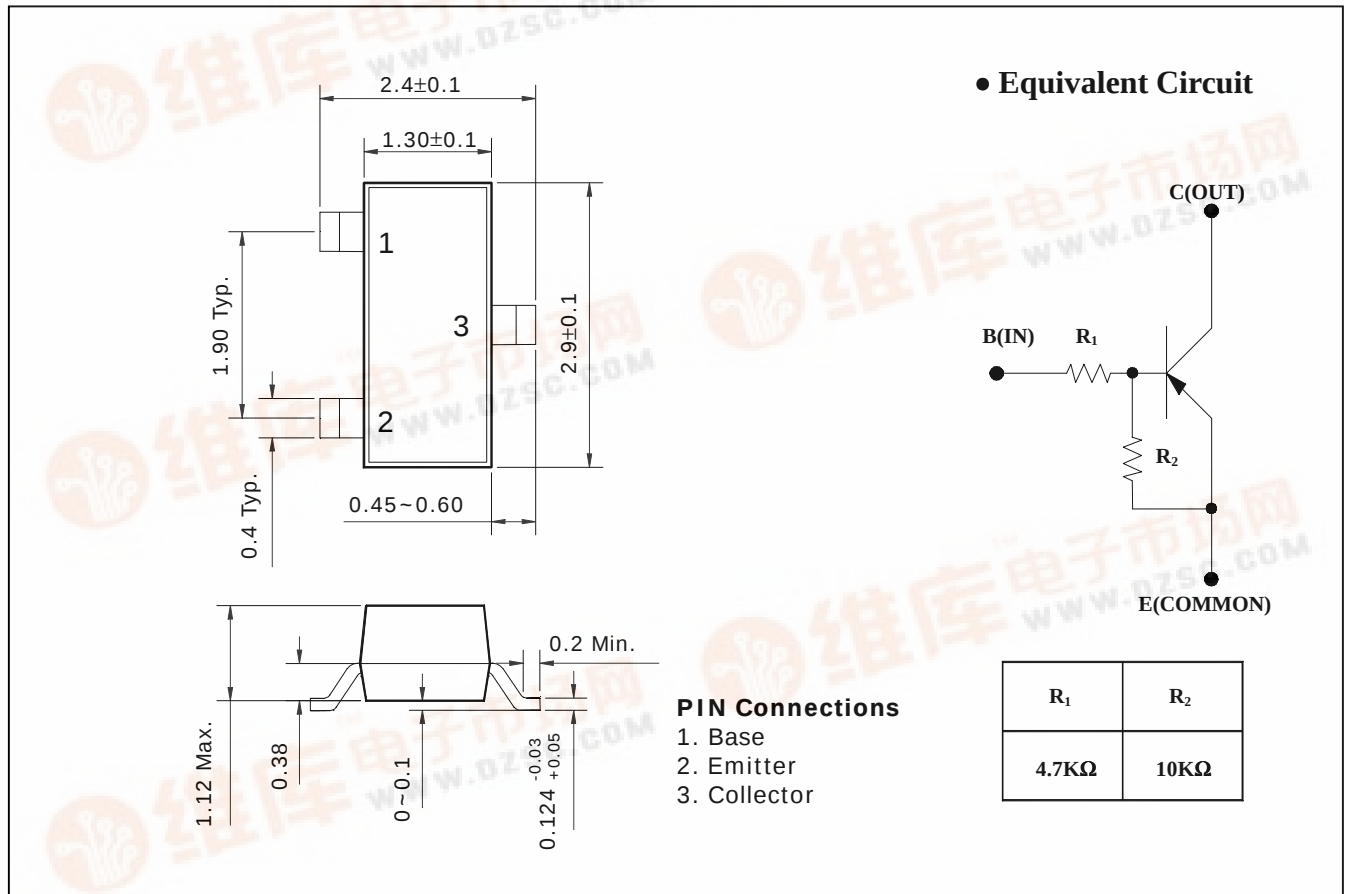
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- High packing density

Ordering Information

Type NO.	Marking	Package Code
SRA2219S	RAC	SOT-23

Outline Dimensions

unit : mm



Absolute maximum ratings

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Out Voltage	V_O	-50	V
Input Voltage	V_I	-20	V
Out Current	I_O	-100	mA
Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ 150	°C

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output Cut-off Current	$I_{O(OFF)}$	$V_O = -50V, V_I = 0$	-	-	-500	nA
DC Current Gain	G_I	$V_O = -5V, I_O = -10mA$	30	-	-	-
Output Voltage	$V_{O(ON)}$	$I_O = -10mA, I_I = -0.5mA$	-	-0.1	-0.3	V
Input Voltage (ON)	$V_{I(ON)}$	$V_O = -0.3V, I_O = -20mA$	-	-1.76	-2.5	V
Input Voltage (OFF)	$V_{I(OFF)}$	$V_O = -5V, I_O = -0.1mA$	-0.3	-0.82	-	V
Transition Frequency	f_T^*	$V_O = -10V, I_O = -5mA$	-	250	-	MHz
Input Current	I_I	$V_I = -5V$	-	-	-1.8	mA

* : Characteristic of Transistor Only

Electrical Characteristic Curves

Fig. 1 $I_O - V_{I(ON)}$

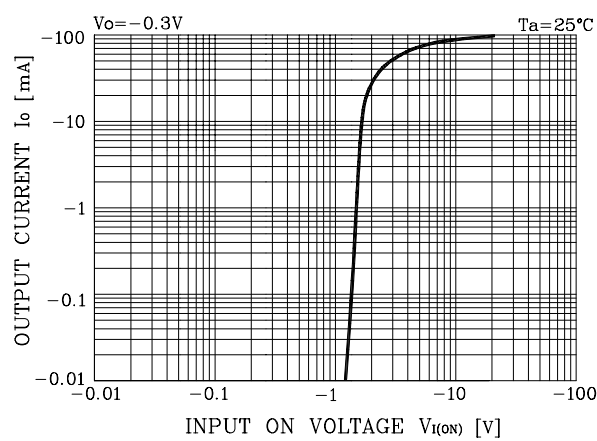


Fig. 2 $I_O - V_{I(OFF)}$

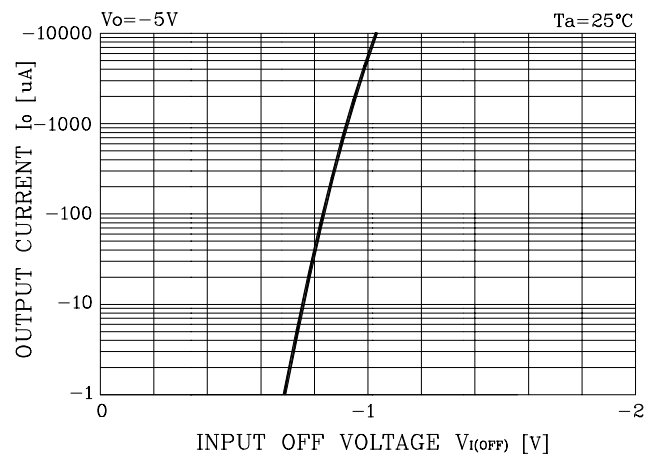


Fig. 3 $G_I - I_O$

